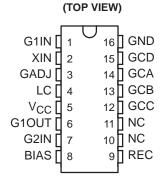
SLSS003 - SEPTEMBER 1983 - REVISED MARCH 1988

- Designed for Use With the TL851 in Sonar Ranging Modules Like the SN28827
- Digitally Controlled Variable-Gain Variable-Bandwidth Amplifier
- Operational Frequency Range of 20 kHz to 90 kHz
- TTL-Compatible
- Operates From Power Sources of 4.5 V to 6.8 V
- Interfaces to Electrostatic or Piezoelectric Transducers
- Overall Gain Adjustable With One External Resistor



N PACKAGE

NC - No internal connection

description

The TL852 is an economical sonar ranging receiver integrated circuit for use with the TL851 control integrated circuit. A minimum of external components is required for operation, and this amplifier easily interfaces to Polaroid's 50-kHz electrostatic transducer. An external 68-k Ω ±5% resistor from BIAS to GND provides the internal biasing reference. Amplifier gain can be set with a resistor from G1IN to GADJ. Required amplifier gain will vary for different applications. Using the detect-level measurement circuit of Figure 1, a nominal peak-to-peak value of 230 mV input during gain step 2 is recommended for most applications. For reliable operation, a level no lower than 50 mV should be used. The recommended detect level of 230 mV can be obtained for most amplifiers with an R1 value between 5 k Ω and 20 k Ω

Digital control of amplifier gain is provided with gain control inputs GCA, GCB, GCC, and GCD. These inputs must be driven synchronously (all inputs stable within 0.1 μ s) to avoid false receive output signals due to invalid logic counts. This can be done easily with the TL851 control integrated circuit. A plot showing relative gain for the various gain steps versus time can be seen in Figure 2. To dampen ringing of the 50-kHz electrostatic transducer, a 5-k Ω resistor from G1IN to XIN is recommended.

An external parallel combination of inductance and capacitance between LC and V_{CC} provides an amplifier with an externally controlled gain and Q. This not only allows control of gain to compensate for attenuation of signal with distance, but also maximizes noise and sidelobe rejection. Care must be taken to accurately tune the L-C combination at operating frequency or gain and Q will be greatly reduced at higher gain steps.

AC coupling between stages of the amplifier is accomplished with a 0.01-mF capacitor for proper biasing.

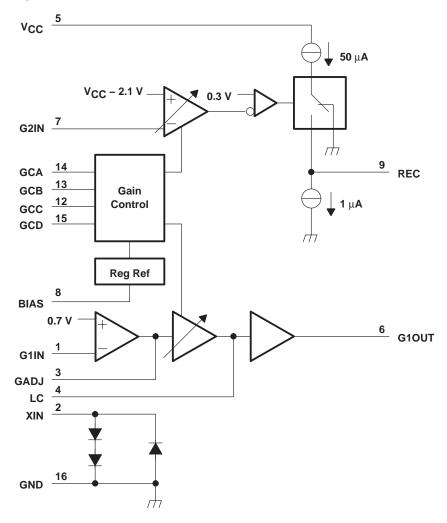
The receive output is normally held at a low level by an internal 1- μ A current source. When an input of sufficient amplitude is received, the output is driven alternately by the 1- μ A discharge current and a 50- μ A charging current. A 1000-pF capacitor is required from REC to GND to integrate the received signal so that one or two noise pulses will not be recognized.

XIN provides clamping for the transformer secondary when used for transducer transmit drive as shown in Figure 4 of the SN28827 data sheet.

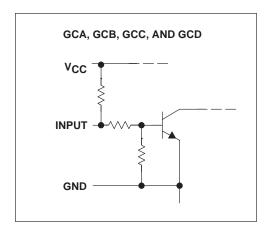
The TL852 is characterized for operation from 0°C to 40°C.



functional block diagram



schematic of gain control inputs





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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Voltage at any pin with respect to GND	- 0.5 V	to 7 V
Voltage at any pin with respect to V _{CC}	– 7 V to	o 0.5 V
XIN input current (50% duty cycle)	±	:60 mA
Continuous power dissipation at (or below) 25°C free-air temperature (see Note 1)	115	50 mW
Operating free-air temperature range	- 40°C to	o 85°C
Storage temperature range	65°C to	150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds		260°C

[†] Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. This is a stress rating only, and functional operation of the device at these or any other conditions beyond those indicated in the recommended operating conditions section of this specification is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: For operation above 25°C, derate linearly at the rate of 9.2 mW/°C.

recommended operating conditions

		MIN	MAX	UNIT
Supply voltage, V _{CC}		4.5	6.8	V
High-level input voltage, VIH	004 000 000 000	2.1		.,
level input voltage, V _{IL} GCA, GCB, GCC, GCD			0.6	V
Bias resistor between BIAS and GND		64	72	kΩ
Operating free-air temperature, T _A		0	40	°C

electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER	DITIONS	MIN TYP	‡ MAX	UNIT	
I A I A A A A A A A A A A A A A A A A A	I _I = 40 mA			2.5	.,
Input clamp voltage at XIN	$I_1 = -40 \text{ mA}$			- 1.5	V
Open-circuit input voltage at GCA, GCB, GCC, GCD	$V_{CC} = 5 V$,	I _I = 0	2.	5	V
High-level input current, I _{IH} , into GCA, GCB, GCC, GCD	$V_{CC} = 5 V$,	V _{IH} = 2 V	- 0.	5	mA
Low-level input current, I _{IL} , into GCA, GCB, GCC, GCD	$V_{CC} = 5 V$,	V _{IL} = 0		- 3	mA
B	$I_{G2IN} = -100 \mu\text{A},$	V _O = 0.3 V		1	
Raceive output current	$I_{G2IN} = 100 \mu\text{A},$	V _O = 0.1 V	- 5	0	μΑ
Supply current, I _{CC}				45	mA

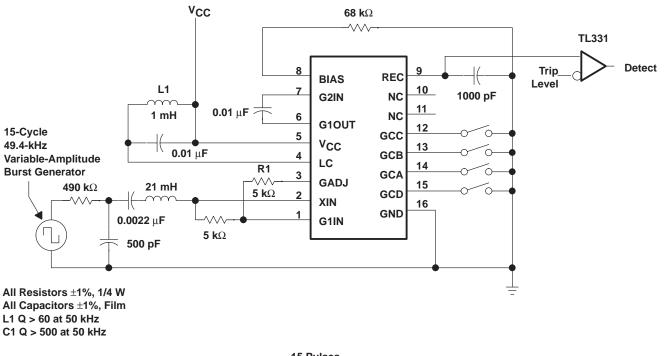
[‡] Typical values are at $V_{CC} = 5$ V and $T_A = 25$ °C.



APPLICATION INFORMATION

detect level versus gain step

Detect level is measured by applying a 15-cycle burst of 49.4 kHz square wave just after the beginning of the gain step to be tested. The least burst amplitude that makes REC reach the trip level is defined to be the detect level. System gain is then inversely proportional to detect level. See the test circuit in Figure 1.



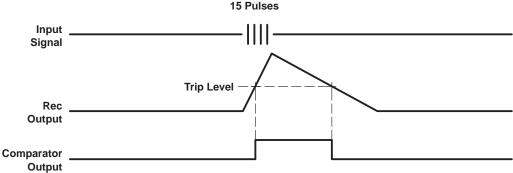


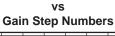
Figure 1. Detect-Level Measurement Circuit and Waveforms

APPLICATION INFORMATION

GAIN STEP TABLE

GCD	GCC	GCB	GCA	STEP NUMBER
L	L	L	L	0
L	L	L	Н	1
L	L	Н	L	2
L	L	Н	Н	3
L	Н	L	L	4
L	Н	L	Н	5
L	Н	Н	L	6
L	Н	Н	Н	7
Н	L	L	L	8
Н	L	L	Н	9
Н	L	Н	L	10
Н	L	Н	Н	11

Receiver Gain



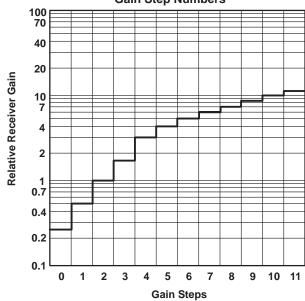


Figure 2





24-Jan-2013

PACKAGING INFORMATION

Orderable Device	Status	Package Type	_		Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
	(1)		Drawing			(2)		(3)		(4)	
TL852CDR	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		TL852C	Samples
TL852CDRG4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		TL852C	Samples
TL852CN	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type		TL852CN	Samples
TL852CNE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type		TL852CN	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) Only one of markings shown within the brackets will appear on the physical device.

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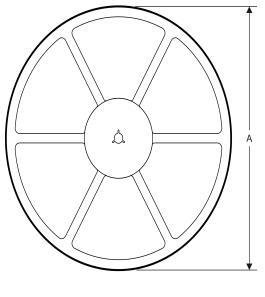
24-Jan-2013

PACKAGE MATERIALS INFORMATION

14-Jul-2012 www.ti.com

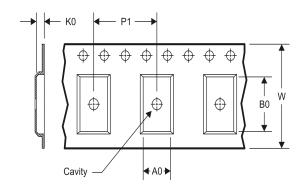
TAPE AND REEL INFORMATION

REEL DIMENSIONS





TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

TAPE AND REEL INFORMATION

*All dimensions are nominal

Device	•	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TL852CDR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1

www.ti.com 14-Jul-2012



*All dimensions are nominal

ĺ	Device	Package Type	Type Package Drawing P		SPQ	Length (mm)	Width (mm)	Height (mm)	
I	TL852CDR	SOIC	D	16	2500	367.0	367.0	38.0	

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



D (R-PDS0-G16)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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